

600 W Half-Bridge LLC evaluation board

EVAL_600W_LLC_12V_C7_D
digital & analog



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General

Description:

The "**EVAL_600W_LLC_12V_C7**" - evaluation board shows how to design a Half-Bridge LLC stage of a server SMPS with the target to meet 80+ Titanium standard efficiency requirements. On this purpose there has been applied latest CoolMOS™ technology [IPP60R180C7](#) 600 V power MOSFET on the primary side and OptiMOS™ low voltage power MOSFET in SuperSO8 [BSC010N04LS](#) in the synchronous rectification secondary stage, in combination with QR CoolSET™ [ICE2QR2280Z](#), hi-low side driver [2EDL05N06PF](#), low-side Gate Driver [2EDN7524F](#) and a LLC Controller [ICE2HS01G](#) for the analog or [XMC4200](#) in the digital version.

Summary of features:

- › Output voltage: 12 V
- › Output current: 50 A
- › Efficiency @ 10% load > 95%
- › Peak efficiency @ 50% load > 97,8%



The following variants are available:

- › 600W 12V LLC **analog** version with CoolMOS™ C7, [IPP60R180C7](#), EVAL_600W_LLC_12V_C7
- › 600W 12V LLC **digital** version with CoolMOS™ C7, [IPP60R180C7](#), EVAL_600W_LLC_12V_C7_D

Example of system understanding: Infineon demo solution for Titanium HV DC/DC stage



Half-Bridge LLC with synchronous rectification in center tap configuration

V_{in}	350-410 V _{DC}
V_{in_nom}	380 V _{DC}
V_{out_nom}	12 V _{DC}
I_{out}	50 A
P_o	600 W
$f_{res} = f_0$	157 kHz
f_{min}	90 kHz
f_{max}	210 kHz
Transformer turns ratio	16:1
C_r	66 nF
L_r	15.5 μ H
L_m	195 μ H

Primary HV MOSFETs
CoolMOS™ IPP60R180C7

- Reduced gate charge (Q_g)
- > Reduced E_{off}
 - > High body diode ruggedness

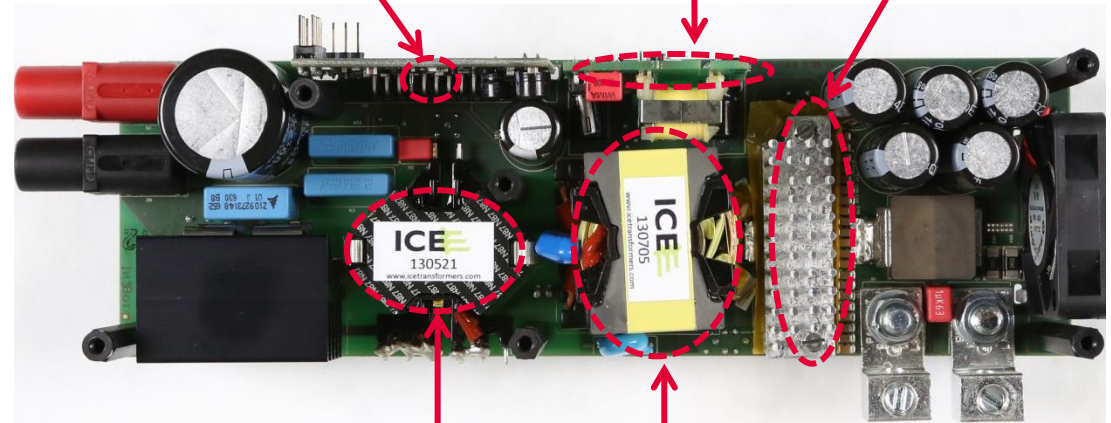
SR MOSFETs
OptiMOS™ BSC010N04LS

- New generation
- > Best FOM $R_{DS(on)} \times Q_g$
 - > Best FOM $R_{DS(on)} \times Q_{oss}$

HB Gate Drive IC
 2EDL05N06PF
Non isolated LS Gate Drive
 2EDN7524F
LLC controller
 Digital XMC4200 / Analog ICE2HS01G

Bias QR Flyback controller
 ICE2QR2280Z

SR MOSFETs
 BSC010N04LS



Resonant inductor **Transformer**
 RM12 core PQ35/35 core

Control board analog & digital

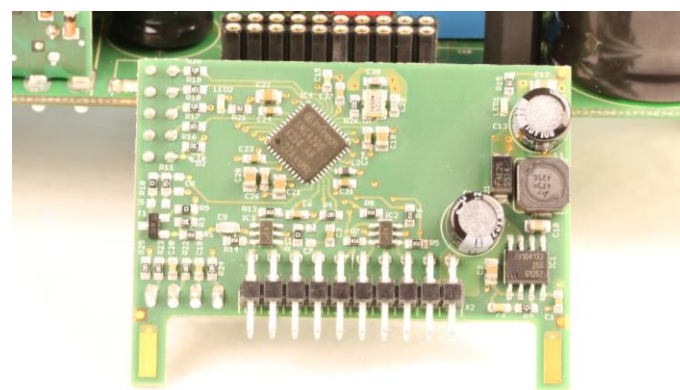
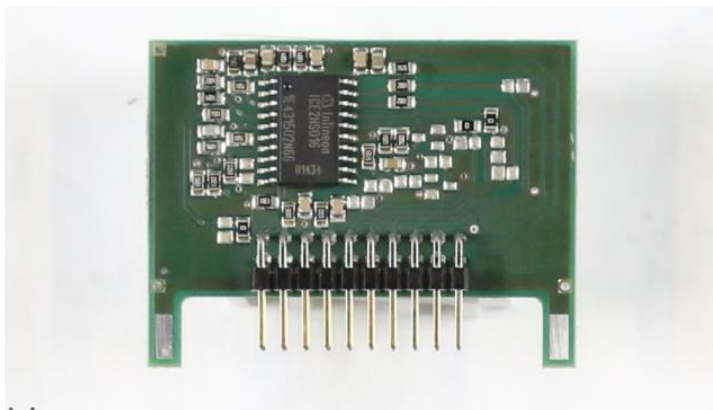
Two possible solution to control Infineon`s 600 W LLC evaluation board

Analog - ICE2HS01G

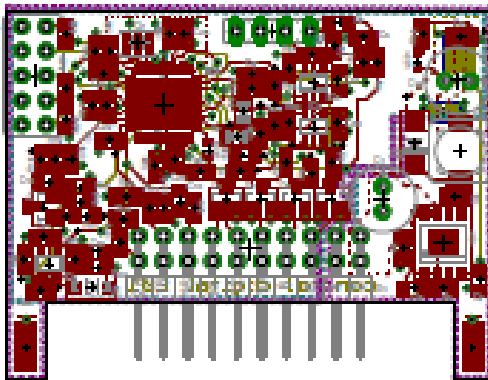
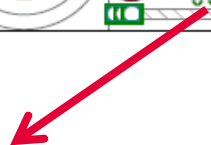
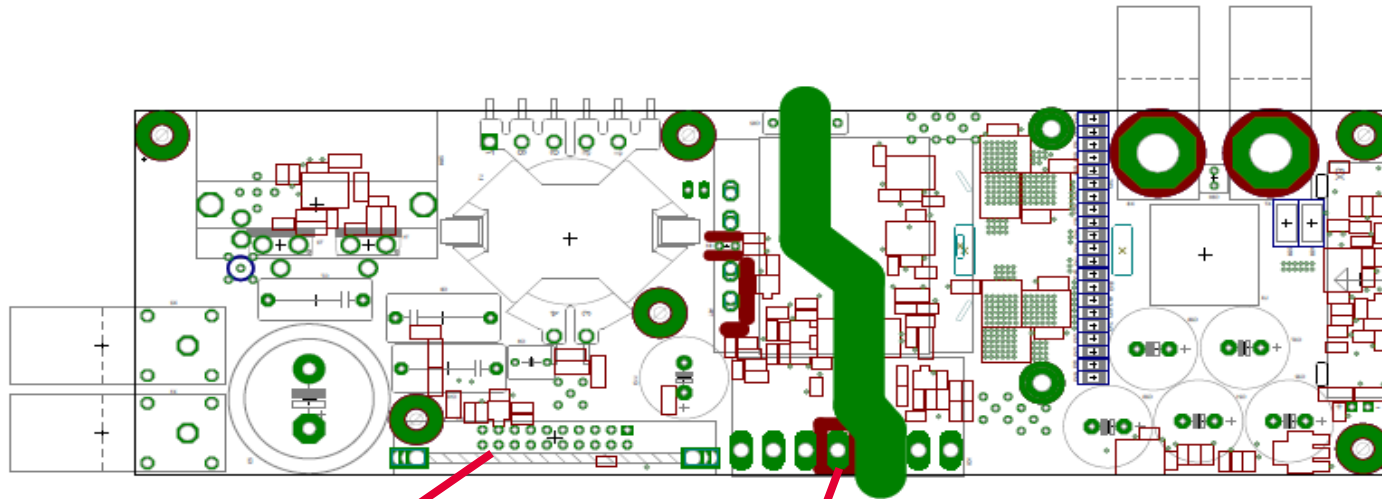
- > Resonant mode controller for Half-Bridge LLC resonant converter with synchronous rectification drives
- > Driving signal for synchronous rectification which support full operation of Half-Bridge LLC resonant converter
- > 20-pin DSO package
- > 30 kHz to 1MHz switching frequency
- > 50% duty cycle for both primary and secondary gate drives
- > Adjustable dead time with high accuracy

Digital - XMC4200-Q48K256 AB

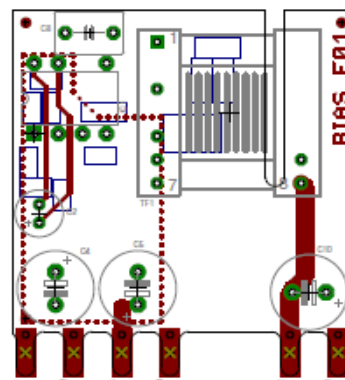
- > ARM® Cortex®-M4, 80 MHz, incl. single cycle DSP MAC and floating point unit (FPU)
- > 8-channel DMA + dedicated DMA for USB
- > USB 2.0 full-speed device
- > CPU Frequency: 80 MHz
- > eFlash: 256 kB including hardware ECC
- > 40 kB SRAM
- > Package: PG-LQFP-48



PCB boards layout: main power board and control and bias daughter boards



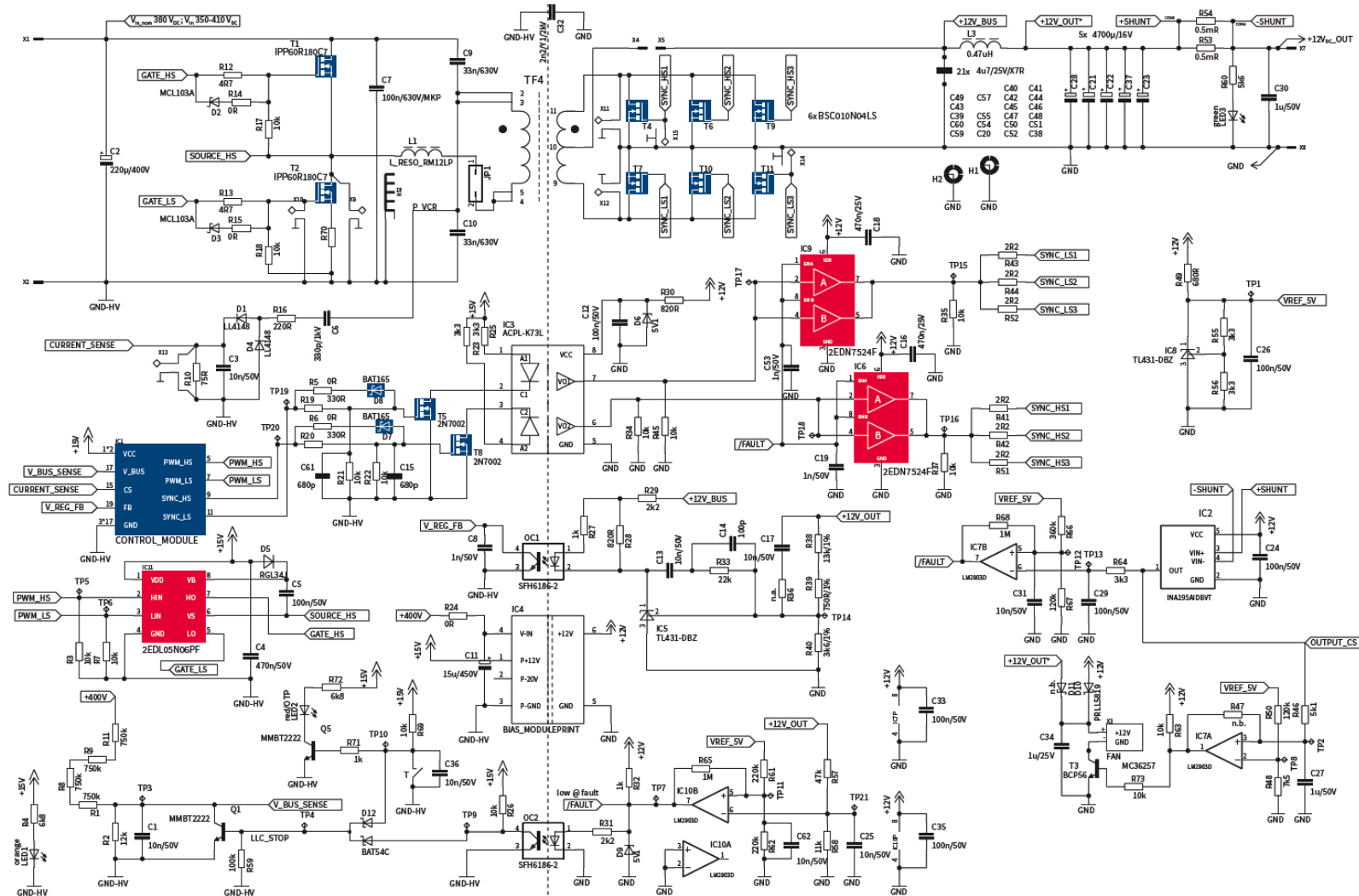
Controller board



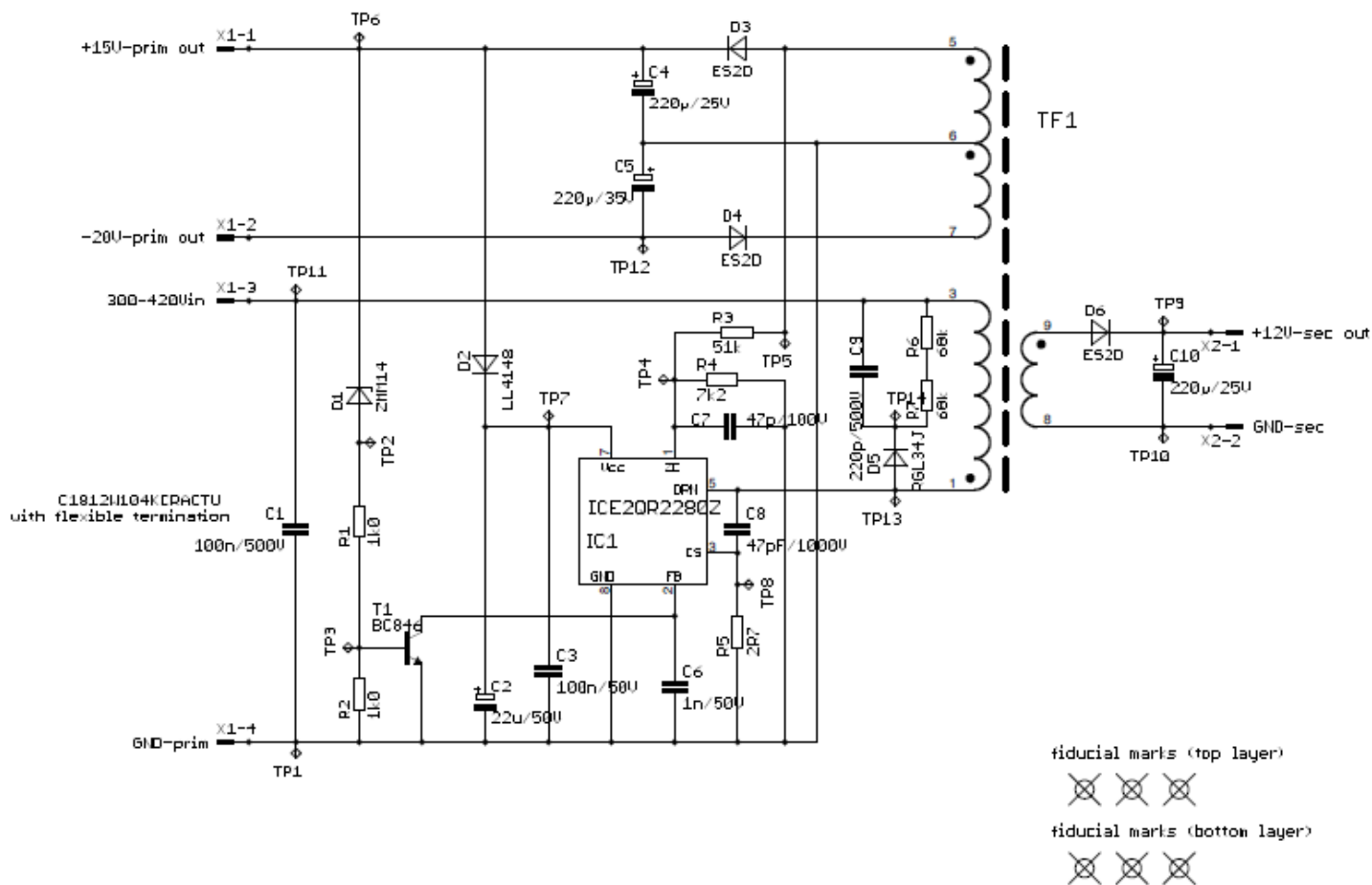
Bias board

- Power density $>20 \text{ W/inch}^3$

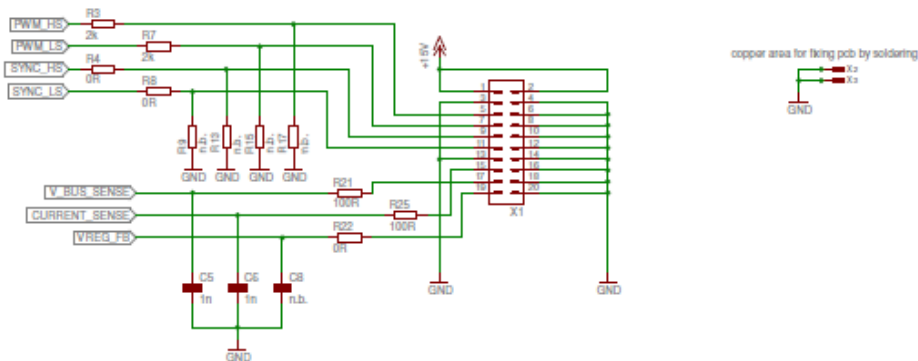
Main power board schematic (digital)



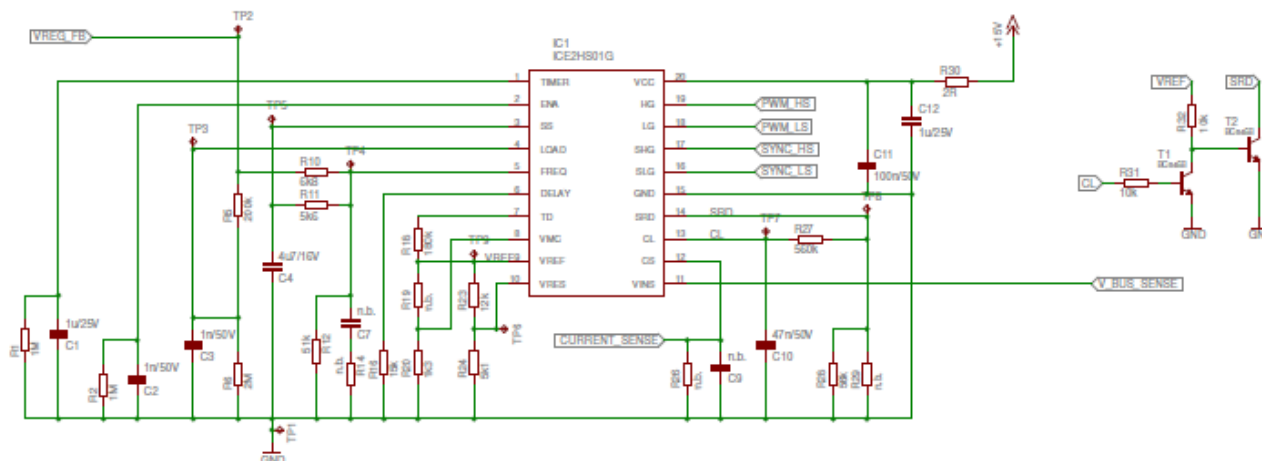
Bias board schematic



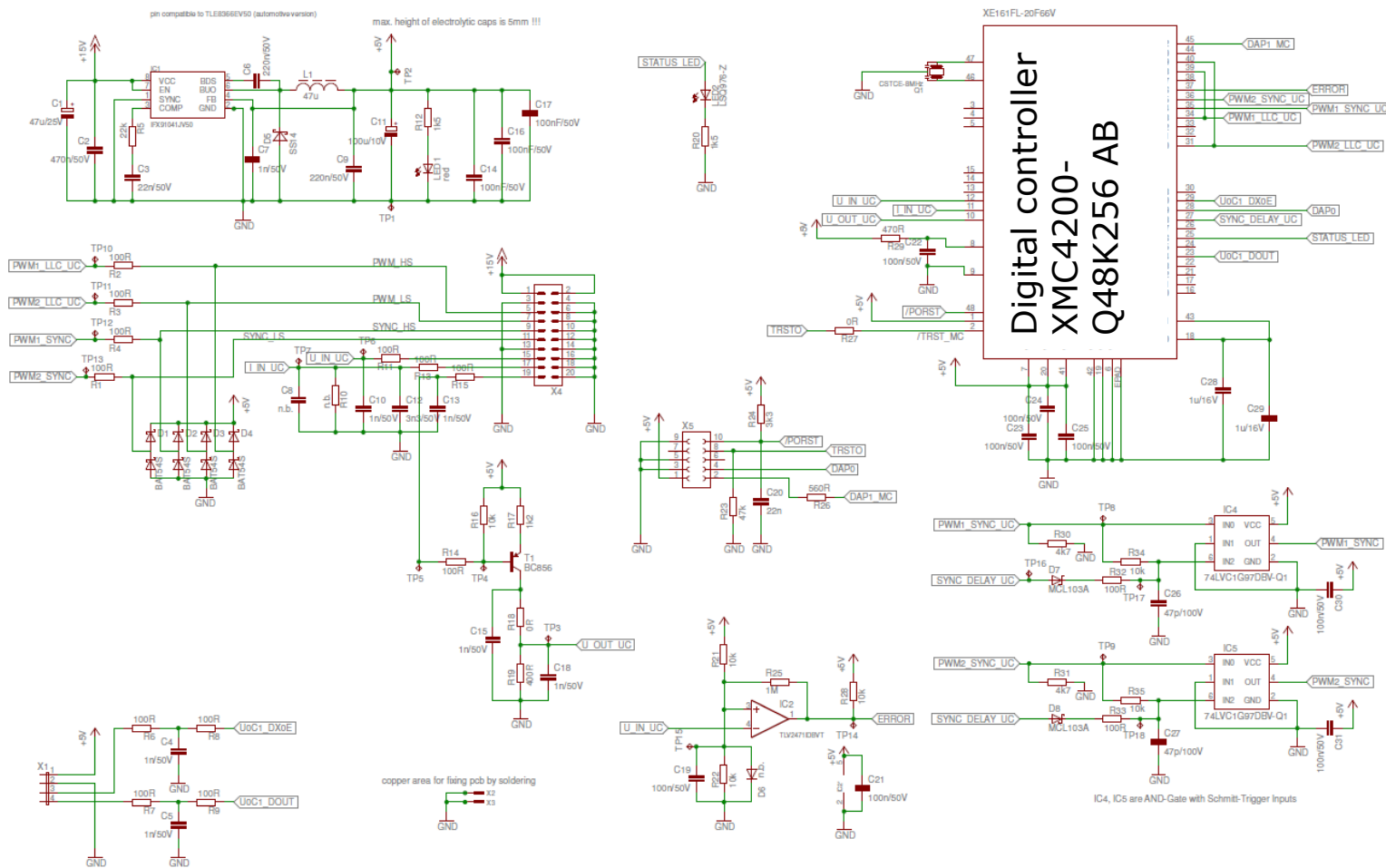
Analog control board schematic



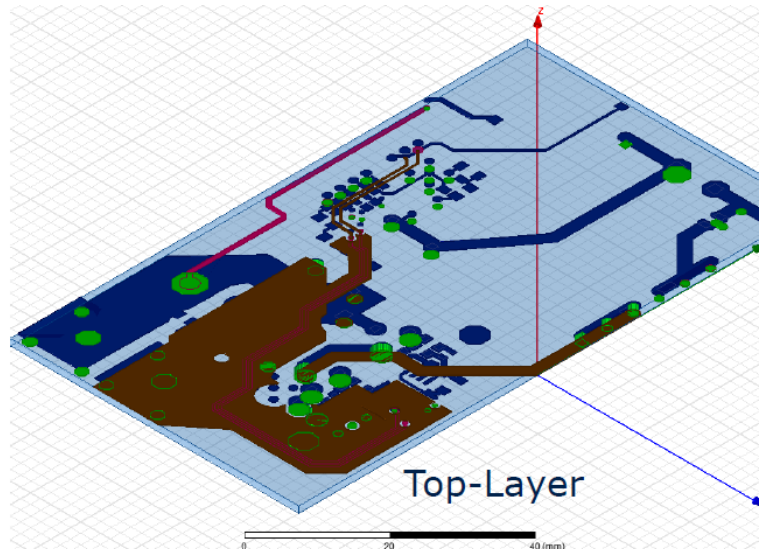
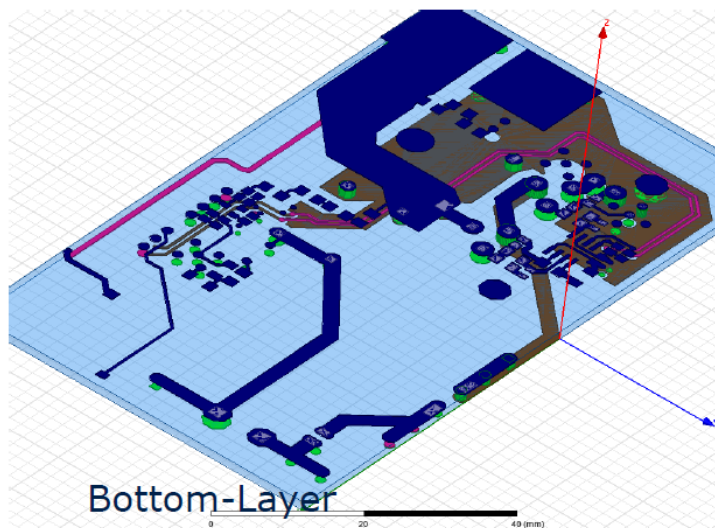
Riducial marks on top layer



Digital control board schematic



PCB structure



PCB-Stackup

Nr	Copper	Isolation
1	<input type="text" value="0.07mm"/>	<input type="text" value="0.15mm"/>
2	<input type="text" value="0.07mm"/>	<input type="text" value="0.93mm"/>
15	<input type="text" value="0.07mm"/>	<input type="text" value="0.15mm"/>
16	<input type="text" value="0.07mm"/>	
Gesamt: 1.51mm		

BOM (rework from digital to analog)

Part	Value	Pcs	Tolerance	Device	Package	Description	Assembling info	Supplier
C3	470n/50V	1		C-EU_C0805	C0805	CAPACITOR	Replace 10n/50V with 470n/50V	
R19	4K3	1	±1%	R-EU_R0805	R0805	RESISTOR	Replace 330R with 4K3	
R20	4K3	1	±1%	R-EU_R0805	R0805	RESISTOR	Replace 330R with 4K3	
R36	56R	1	±1%	R-EU_R0805	R0805	RESISTOR	Assemble n.a. with 56R	
IC1	Board	1		Board	PCB	Analog_Controlcard		IFX

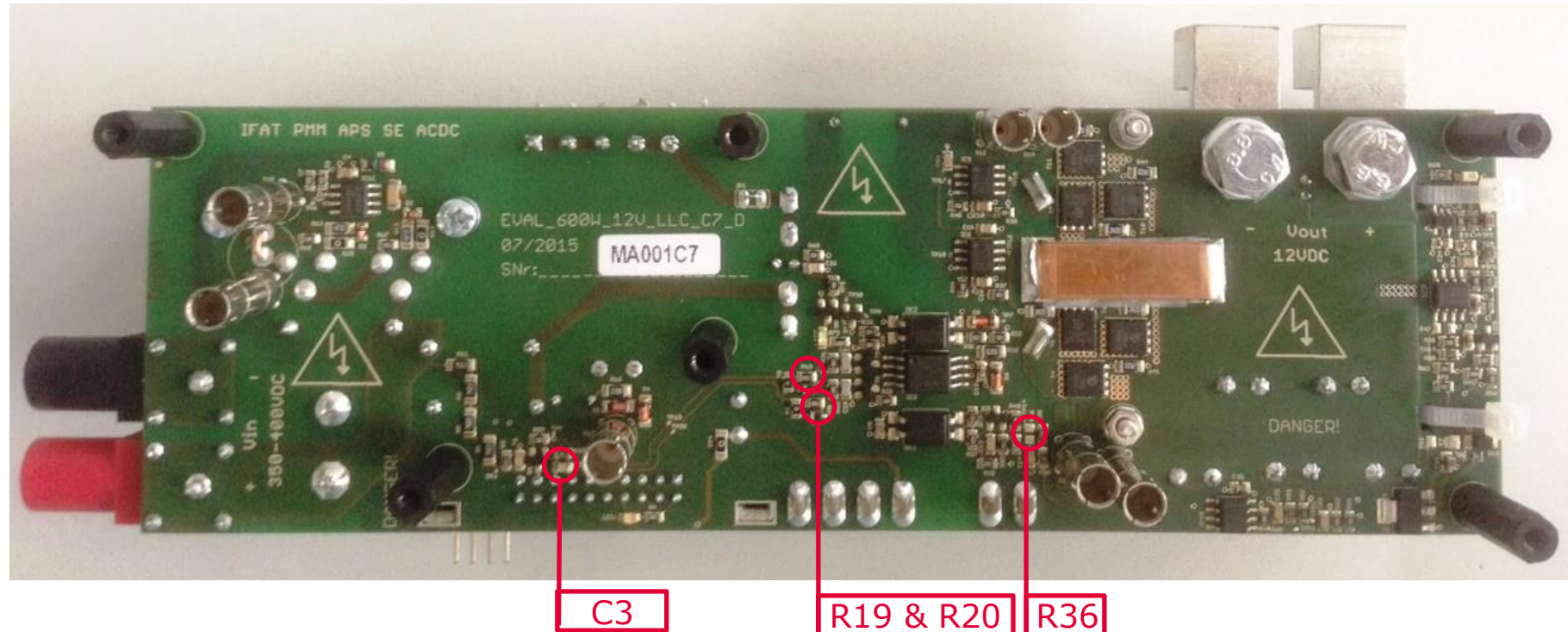


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I General description

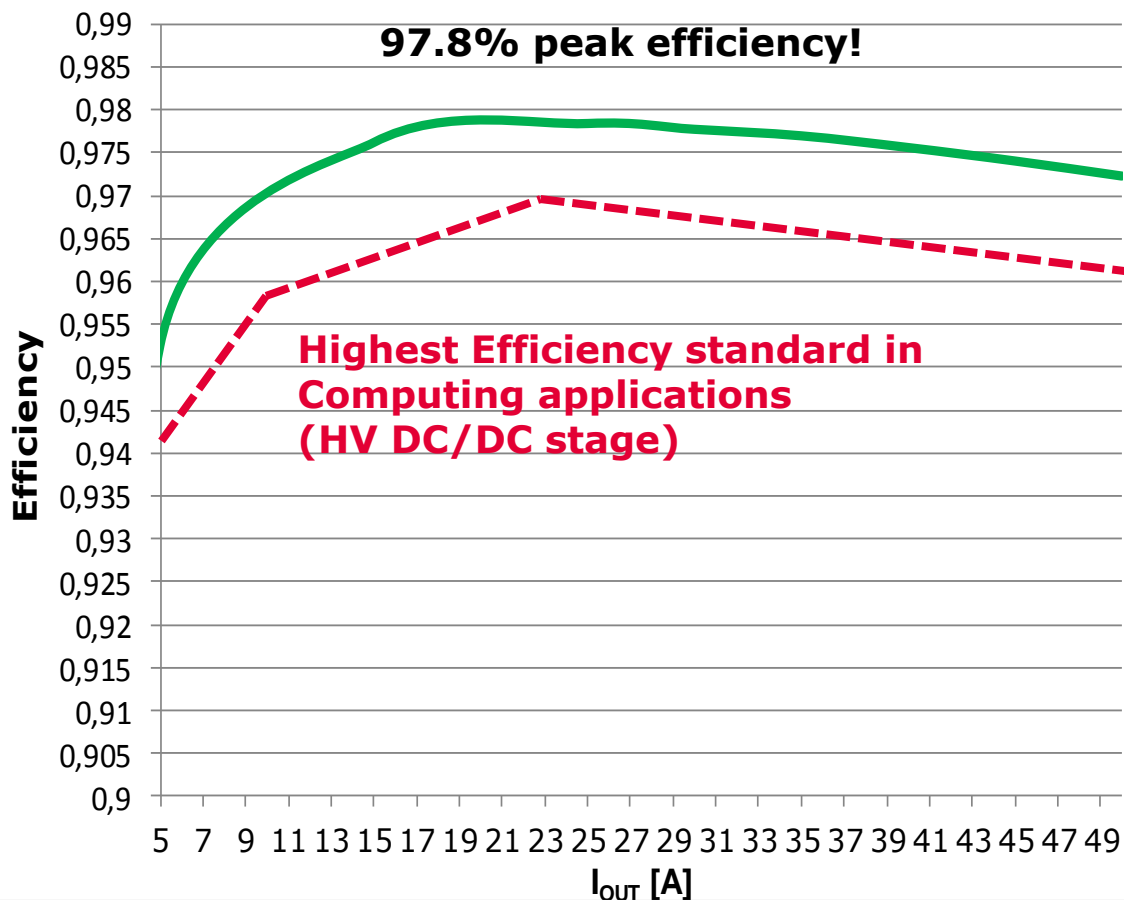
II Efficiency results

III Design concept

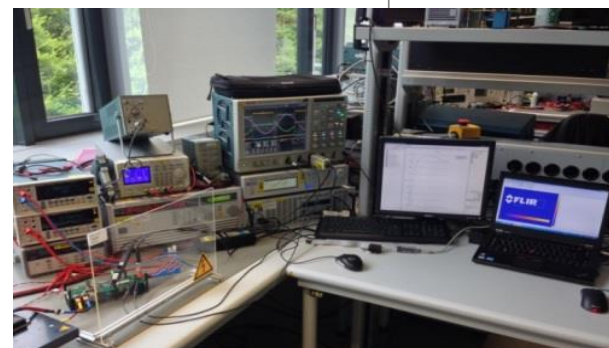
Automated efficiency measurement

Combination of converter design (resonant tank, transformer) and proper HV device election

Proper selection of SR LV device and secondary side



- > Output voltage: 12 V_{DC}
- > Output current: 50 A
- > Efficiency: > 95% @ 10% load, V_{in} = 380 V_{DC}
- > Efficiency max: 97.8%, V_{in} = 380 V_{DC}



0.1% Total accuracy

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Design procedure: input data

$$n = \frac{V_{in_nom}}{2 \cdot V_{out_nom}}$$

$$M_{min} \equiv K_{min}(Q, m, F_x) = \frac{n \cdot V_{o_min}}{V_{in_max} / 2}$$

$$M_{max} \equiv K_{max}(Q, m, F_x) = \frac{n \cdot V_{o_max}}{V_{in_min} / 2}$$

Resonant tank components and related resonant frequencies

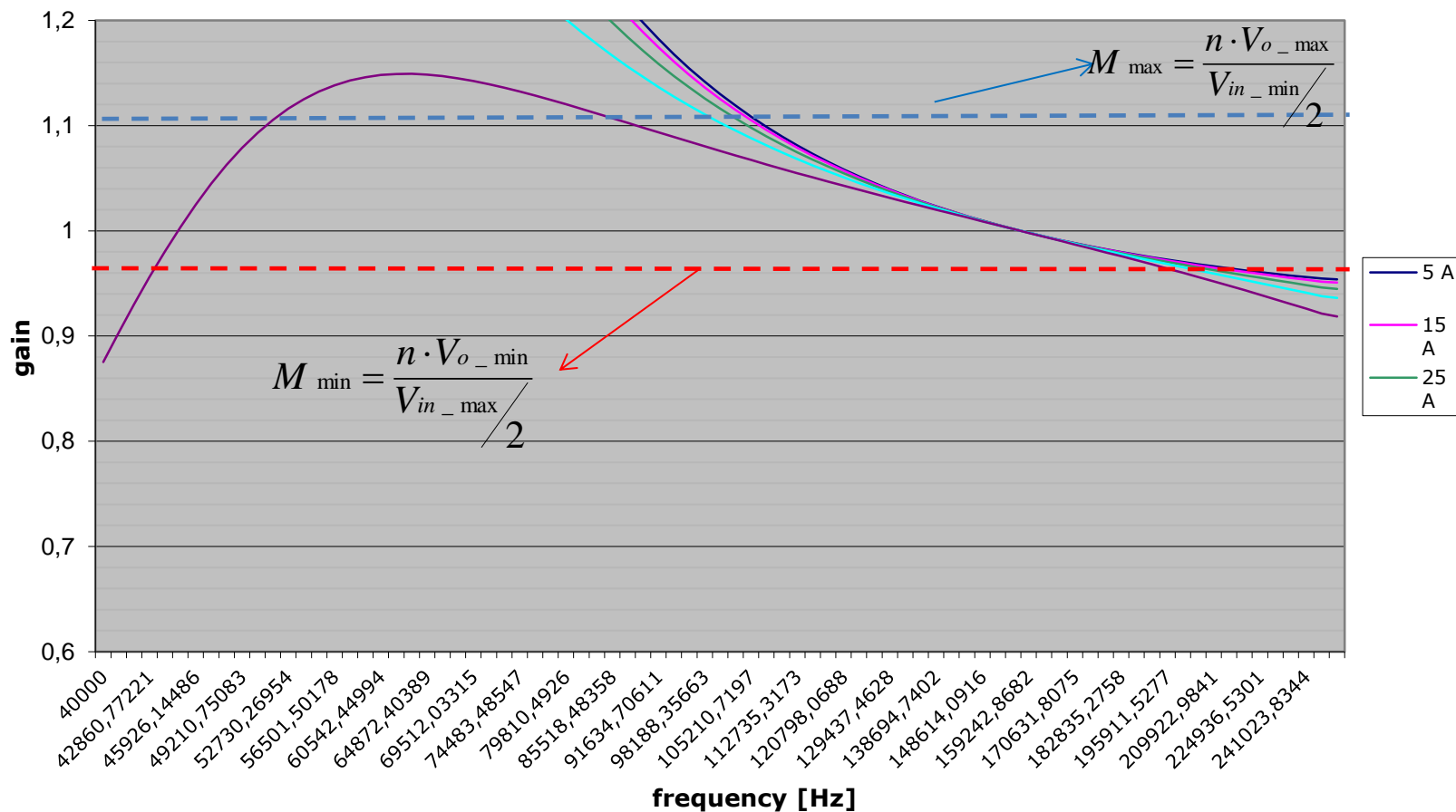
- › $n = V_{in_nom} / (2 \times V_o) = 380 / (2 \times 12) \approx 16$
- › $L_m = 195 \mu H$
- › $L_r = 15.5 \mu H$
- › $L_n = L_m / L_r = 12.5$
- › $C_r = 66 nF$

$$f_o = \frac{1}{2\pi \cdot \sqrt{L_r \cdot C_r}} = 157 kHz$$

$$f_p = \frac{1}{2\pi \cdot \sqrt{(L_r + L_m) \cdot C_r}} = 42.7 kHz$$

Gain curves

DC - gain curve (600W LLC hardware revision C7)



Energy related calculations (Ref. IPP60R180C7 device parameters)

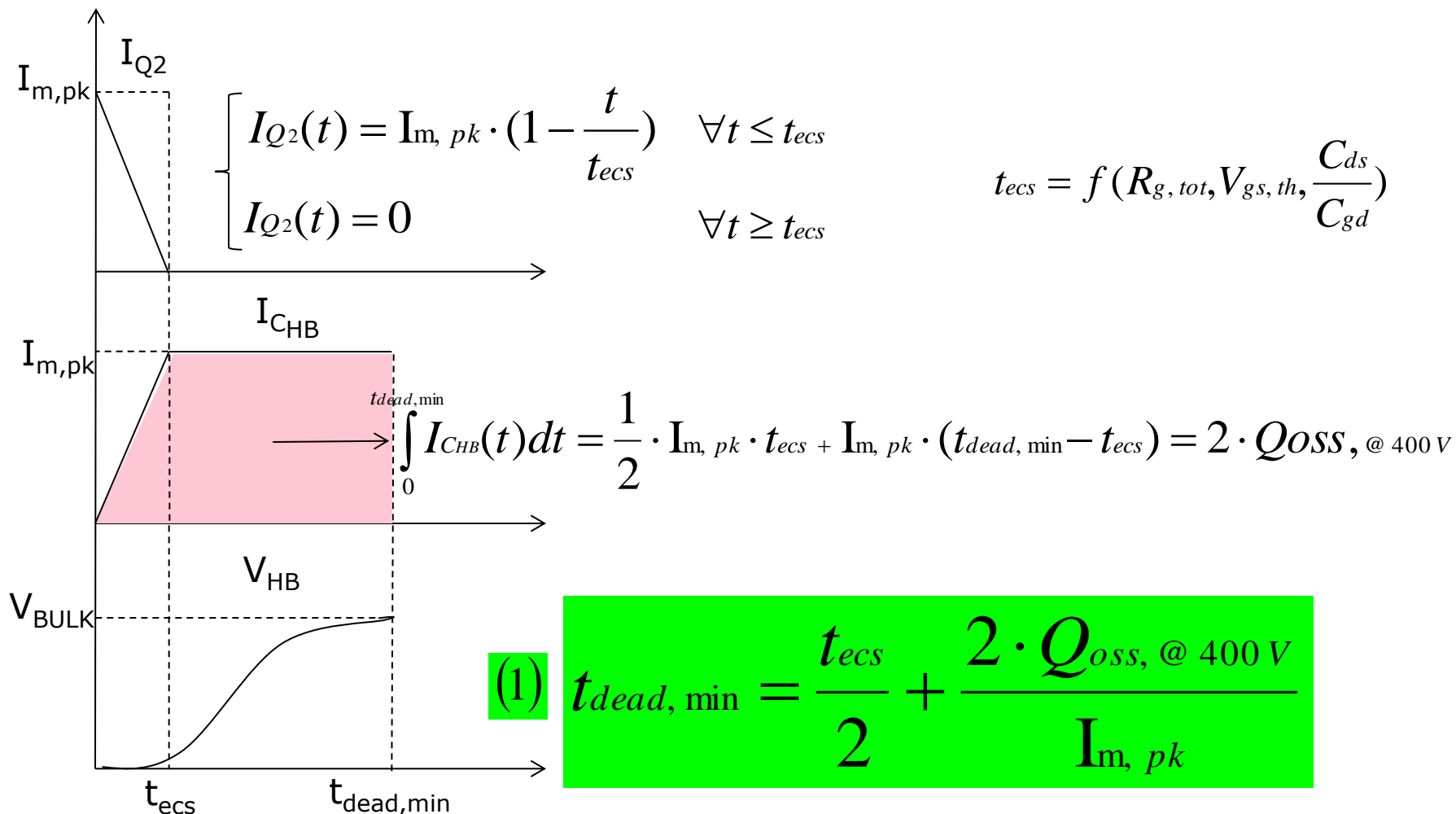
$$I_{mag_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_max} \cdot L_m} = 0.672 \text{ A}$$

$$E_{nres_min} = \frac{1}{2} \cdot (L_m + L_r) \cdot I_{mag_min}^2 = 95.1 \mu\text{J}$$

$$E_{ncap_max} = \frac{1}{2} \cdot (2Co(er)) \cdot V_{DS_max}^2 \approx 9 \mu\text{J}$$

$$\Rightarrow E_{nres_min} > E_{ncap_max}$$

$Q_{oss}, I_{mag,pk}, t_{dead,min}, t_{ecs}$ relationship



Time related calculations (Ref. IPP60R180C7 device parameters)

$$I_{mag_min} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_max} \cdot L_m} = 0.672 \text{ A}$$

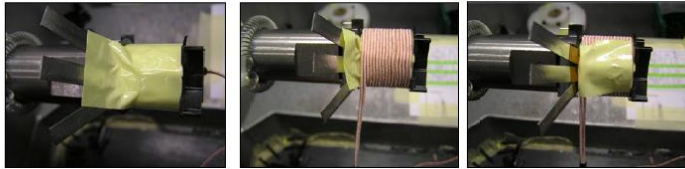
$$I_{mag_max} = \frac{2 \cdot \sqrt{2}}{\pi} \cdot \frac{n \cdot V_o}{2\pi \cdot f_{sw_min} \cdot L_m} = 1.66 \text{ A}$$

$$t_{dead, min} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, max}} \approx 130 \text{ nsec}$$

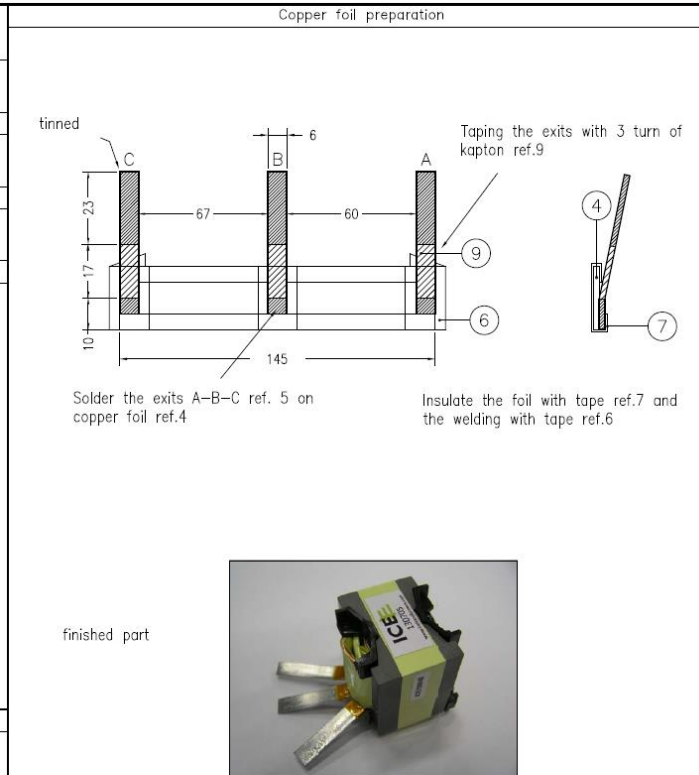
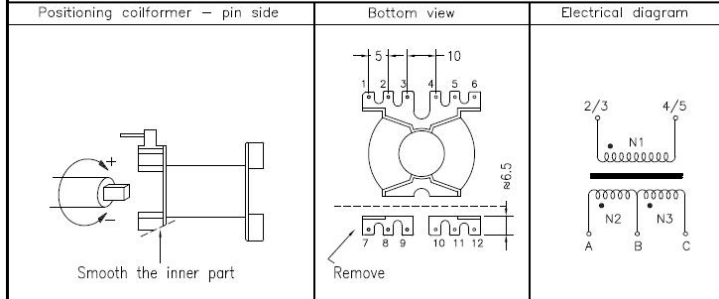
$$t_{dead, max} = \frac{t_{ecs}}{2} + \frac{2 \cdot Q_{oss, @ 400V}}{I_{mag, min}} \approx 311 \text{ nsec}$$

Main transformer structure: PQ35/35 core with TDK PC95 ferrite material

Wind.	Conductor	N°. of Turns	R o p e r	Output pin	Winding layer	N°. layer	Sleeves			Notes	
							Col.	Ref. M.L.	Free length mm.		
N1a	2xLitz 90x0.10 Ref.3	0	+	2-3 *	8	1	Re	8	20	/	2 wires in 1 sleeve.
Insulation: 3 turns of polyester adhesive tape Ref.6											
N2	Copper foil	0	+	A	1	1	/	/	/	/	
N3	0.50x0.20 Ref.4	1	+	B C	1	1	/	/	/	/	
Insulation: 1 turn of polyester adhesive tape Ref.6 + 1 piece as showed in pictures											
N1b	2xLitz 90x0.10 Ref.3	0	+	* 4-5	8	1	Re	8	20	/	2 wires in 1 sleeve. Don't need correspondence
Insulation: 3 turns of polyester adhesive tape Ref.6											



Insert piece of tape after the insulation of N2-N3. Wind N1b. Refold tape, block and connect the wires to pin



REV	APPR DATE	REF. MOD.	DESCRIPTION OF MODIFICATION	EDITING	CHECKING AND APPROVAL
02	21.07.15		Inserted label and pictures	C. Picciani	D. Di Giorgio
01	24.01.14		Release	C. Picciani	D. Di Giorgio

TRANSFORMERS

Mod. AQ 05.09	DOCUMENT TYPE	CODE	REVISION	RELEASE DATE	PAGE
	P.F.	8065.0703.001	02	24.01.14	1of2

Resonant choke: RM12 core, material N87

Wind.	Conductor type	N. of windings	R.P.C.	output pin	Winding Layer	N. of Layer	Tube			Notes
							Color	Ref.	Length mm	
N1	Litz 120x0.10 Ref. 4	0 9	+	7+8+9 10+11	9	1	/ Red	/ 6	/ 20	Perpendicular crossing on tape ref.5

Insulation: 2 turns polyester tape Ref.5

Bill of materials	
Ref.	Description
1	Coil Former RM12 12pins (B65816-C1512-T1 Epcos mat.Valox420 E45329)
2	Ferrite core RM12 gap 1.1mm (B65815-R87 Epcos)
3	RM12 clamp (B65816-A2002 Epcos)
4	Litz wire 120x0.100mm G1 (155°C E125660 or equivalent)
5	Polyester adhesive tape H=16mm thickness 0.06mm (P31 E178430 or equivalent)
6	Tube glass/silicone Ø1,5mm 4KV 20mm (GVES2500 E311983 or equivalent)
7	Activator for epoxy resin (IN1005 or equivalent)
8	Epoxy resin (36T or equivalent)
9	PVC label 24x12mm
10	Insulating varnish classH (AC43 E317427 or equivalent)
11	Polyestere label 4.7x14mm (7816 MH16411 or equivalent)

Assembling

Serial number: ICEAANNNN * (11)

Fix core/coilformer with ref. 7+8

Varnish with ref.10

Dimensions in millimeter
RoHS compliant

Electrical test

N°.	Test type	Test conditions	Limits
1	Inductance	7+8+9-10+11 @ 10 kHz - 100 mV	from 11.9 to 16.1 µH

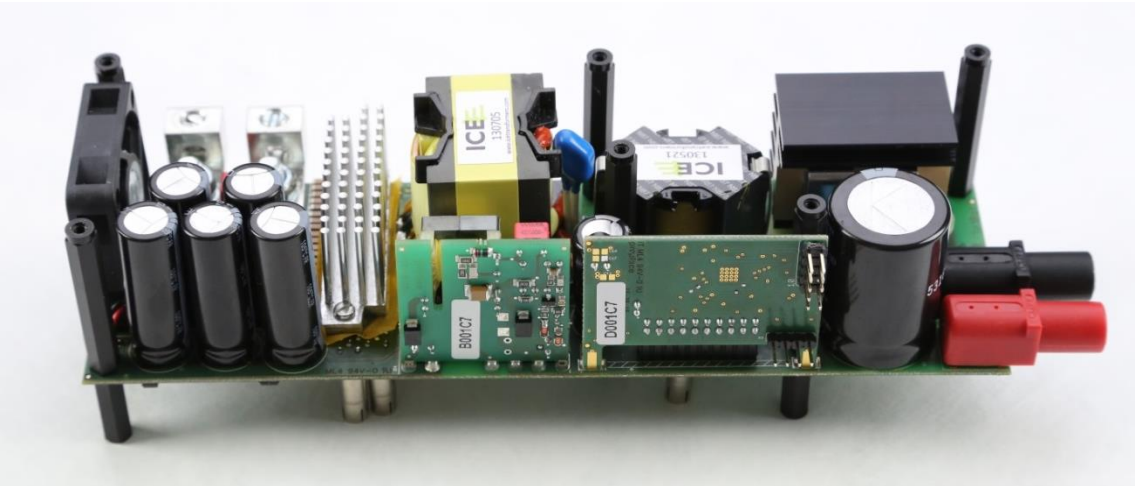
Winding rotation

Bottom View

Electrical drawing

Mod.	DOCUMENT TYPE	CODE	REVISION	EMISSION DATE	PAGE
AQ 05.09	P.F.	8017.0901.012	02	23.01.14	1 of 1

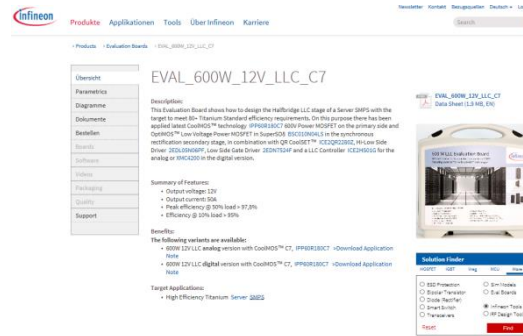
Evaluation board EVAL_600W_12V_LLC_C7



Support slides 600W LLC evaluation board

Evaluation board page

- Technical description
- Datasheets
- Parameters
- Related material
- Videos



- [EVAL_600W_12V_LLC_C7](#)

Product family pages

- Product brief
- Application notes
- Selection guides
- Datasheets and portfolio
- Videos
- Simulation models



- [650V CoolMOS™ C7](#)
- [XMC 32-Bit Industrial Microcontroller](#)
- [Resonant Mode Controller](#)
- [OptiMOS™ 5 40V and 60V](#)





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